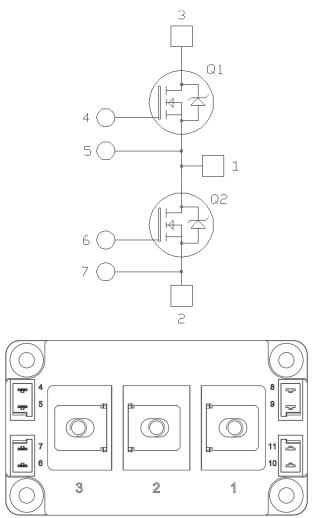


Phase Leg SiC Power Module

Product Overview

The MSCSM120AM027D3AG device is a full bridge 1200V, 733A phase leg silicon carbide (SiC) MOSFET power module.



Note: All ratings at T_J = 25 °C, unless otherwise specified.

Δ CAUTION These devices are sensitive to electrostatic discharge. Proper handling procedures must be followed.

Features

The following are the key features of the MSCSM120AM027D3AG device:

- SiC Power MOSFET
 - Low R_{DS(on)}
 - High temperature performance
 - Kelvin source for easy drive
- High level of integration
- M6 power connectors
- Aluminum Nitride (AIN) substrate for improved thermal performance

Benefits

•

The following are the benefits of MSCSM120AM027D3AG device:

- High efficiency converter
- Stable temperature behavior
- Direct mounting to heatsink (isolated package)
- Low junction-to-case thermal resistance
- RoHS compliant

Application

The MSCSM120AM027D3AG device is designed for the following applications:

- Welding converters
- Switched mode power supplies
- Uninterruptible power supplies
- EV motor and traction drive

1. Electrical Specifications

This section provides the electrical specifications of the MSCSM120AM027D3AG device.

1.1 SiC MOSFET Characteristics (Per SiC MOSFET)

The following table lists the absolute maximum ratings per SiC MOSFET of the MSCSM120AM027D3AG device.

Table 1-1. Absolute Maximum Ratings

Symbol	Parameter		Maximum Ratings	Unit
V _{DSS}	Drain-Source voltage	Drain-Source voltage		V
I _D			733 ¹	A
			584 ¹	
I _{DM}	Pulsed drain current		1400	
V _{GS}	Gate-Source voltage		-10/23	V
R _{DS(on)}	Drain-Source ON resistance		3.5	mΩ
P _D	Power dissipation	T _C = 25 °C	2970	W

Note:

1. SiC MOSFET device specification, but the output current must be limited due to the size of the power connectors.

The following table lists the electrical characteristics per SiC MOSFET of the MSCSM120AM027D3AG device.

 Table 1-2. Electrical Characteristics

Symbol	Characteristic	Test Conditions		Min.	Тур.	Max.	Unit
I _{DSS}	Zero gate voltage drain current	V _{GS} = 0V V _{DS} = 1200V		—	90	900	μΑ
R _{DS(on)}	Drain–Source on	V _{GS} = 20V	T _J = 25 °C		2.8	3.5	mΩ
	resistance I _D = 360A	I _D = 360A	T _J = 175 °C	_	4.5		
V _{GS(th)}	Gate threshold voltage	$V_{GS} = V_{DS}$ $I_D = 27 \text{ mA}$		1.8	2.8	—	V
I _{GSS}	Gate–Source leakage current	V _{GS} = 20V; V _{DS} = 0V		_	_	900	nA

Electrical Specifications

The following table lists the dynamic characteristics per SiC MOSFET of the MSCSM120AM027D3AG device.

Symbol	Characteristic	Test Conditions		Min.	Тур.	Max.	Unit	
C _{iss}	Input capacitance	V _{GS} = 0V		_	27	_	nF	
C _{oss}	Output capacitance	V _{DS} = 1000V			2.43	_		
C _{rss}	Reverse transfer capacitance	f = 1 MHz			0.23			
Qg	Total gate charge	V _{GS} = -5V/20V			2088	<u> </u>	nC	
Q _{gs}	Gate-Source charge	V _{Bus} = 800V I _D = 360A			369			
Q _{gd}	Gate-Drain charge				450	_		
T _{d(on)}	Turn-on delay time	$V_{GS} = -5V/20V$ $V_{Bus} = 600V$ $I_D = 450A$ $R_{G(on)} = 4.7\Omega$ $R_{G(off)} = 1.8\Omega$	V _{GS} = -5V/20V T _J = 15	T _J = 150°C		74		ns
Tr	Rise time		_{G(on)} = 4.7Ω		96			
T _{d(off)}	Turn-off delay time				150			
T _f	Fall time				51			
Eon	Turn-on energy	V _{GS} = -5V/20V	T _J = 150 °C		16	_	mJ	
E _{off}	Turn-off energy	$V_{Bus} = 600V$ $I_D = 450A$ $R_{G(on)} = 4.7\Omega$ $R_{G(off)} = 1.8\Omega$	T _J = 150 °C		9.2			
R _{Gint}	Internal gate resistance			_	0.65	_	Ω	
R _{thJC}	Junction-to-case thermal resistance				—	0.051	°C/W	

Table 1-3. Dynamic Characteristics

The following table lists the body diode ratings and characteristics per SiC MOSFET of the MSCSM120AM027D3AG device.

Table 1-4. Body Diode Ratings and Characteristics

Symbol	Characteristic	Test Conditions	Min.	Тур.	Max.	Unit
V _{SD}	Diode forward voltage	V _{GS} = 0V; I _{SD} = 360A		4	_	V
		$V_{GS} = -5V; I_{SD} = 360A$	—	4.2		
t _{rr}	Reverse recovery time	I _{SD} = 360A; V _{GS} = -5V		90		ns
Q _{rr}	Reverse recovery charge	V_{R} = 600V; di _F /dt = 9000 A/µs		4950		nC
I _{rr}	Reverse recovery current			122		А

Electrical Specifications

1.2 Thermal and Package Characteristics

The following table lists the thermal and package characteristics of the MSCSM120AM027D3AG device.

Symbol	Characteristics	Characteristics			Max.	Unit
V _{ISOL}	RMS isolation voltage, any termin	RMS isolation voltage, any terminal to case t =1 min, 50 Hz/60 Hz			—	V
TJ	Operating junction temperature ra	Operating junction temperature range			175	°C
T _{JOP}	Recommended junction temperat	Recommended junction temperature under switching conditions			T _{Jmax} –25	
T _{STG}	Storage temperature range	Storage temperature range			125	
T _C	Operating case temperature	Operating case temperature			125	
Torque	Mounting torque	For terminals	M6	3	5	N.m
		To heatsink	M6	3	5	
Wt	Package weight			_	350	g

Table 1-5. Thermal and Package Characteristics

Electrical Specifications

1.3 Typical SiC MOSFET Performance Curve

This section shows the typical SiC MOSFET performance curves of the MSCSM120AM027D3AG device.

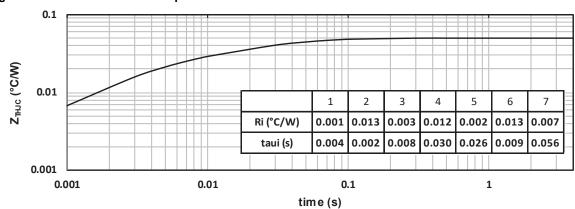
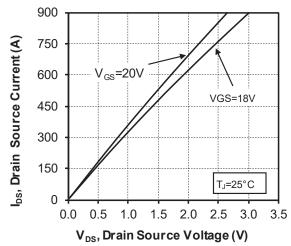


Figure 1-1. Maximum Thermal Impedance







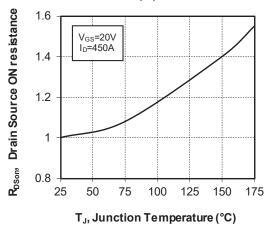
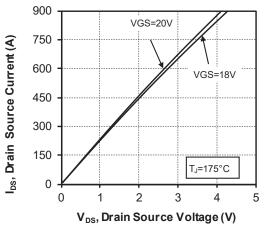
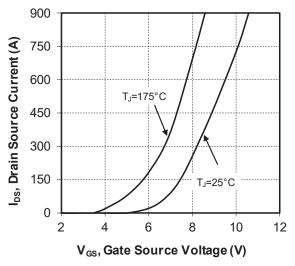


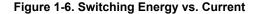
Figure 1-3. Output Characteristics, T_J = 175 °C

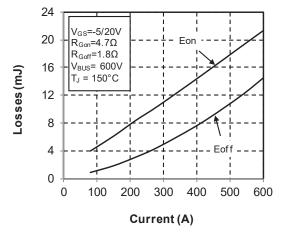


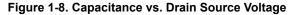


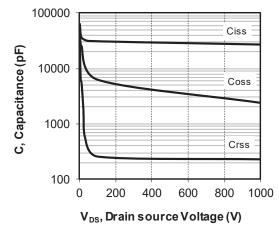


Electrical Specifications











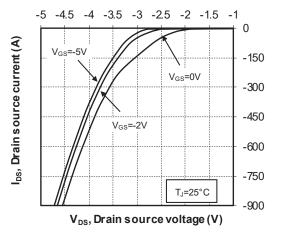


Figure 1-7. Switching Energy vs. Rg

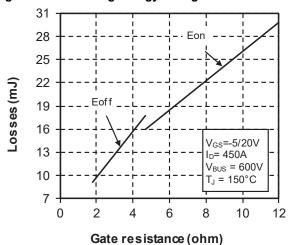
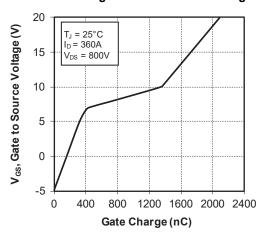
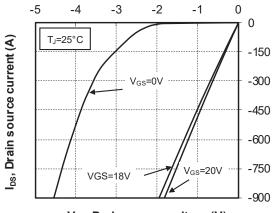


Figure 1-9. Gate Charge vs. Gate Source Voltage







V_{DS}, Drain source voltage (V)

Electrical Specifications

0

0

-150

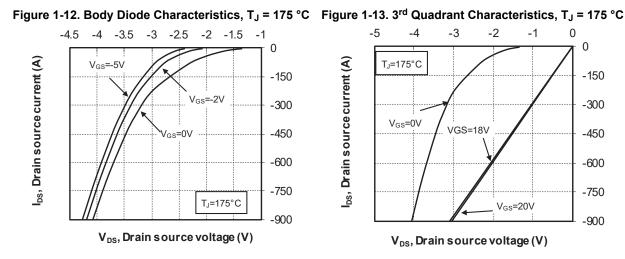
-300

-450

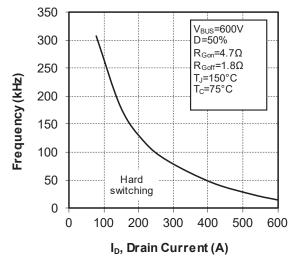
-600

-750

-900







Package Specifications

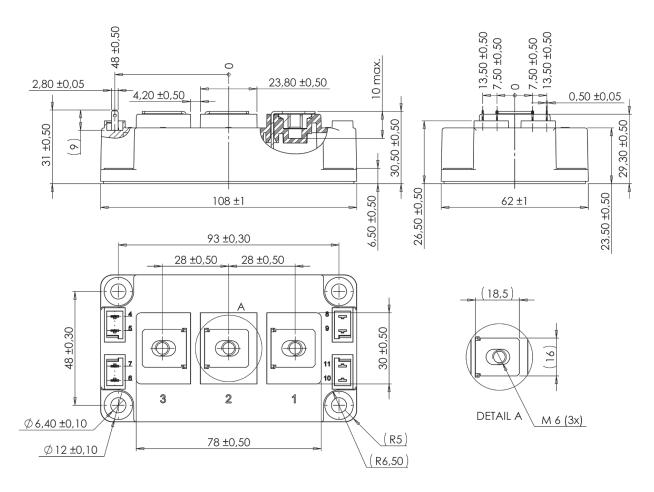
2. Package Specifications

The following section shows the package specification of the MSCSM120AM027D3AG device.

2.1 Package Outline

The following figure shows the package outline drawing of the MSCSM120AM027D3AG device. The dimensions in the following figure are in millimeters.

Figure 2-1. Package Outline Drawing



Note: See AP1908—Mounting instruction for D3 and D4 Power Modules for more information.

3. Revision History

Revision	Date	Description
A	06/2022	Initial Revision.

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